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Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

## **Quality Overview**

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
  - Class Q Military
  - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



April 1992 Revised May 2005

## 74ABT162244

# 16-Bit Buffer/Line Driver with 25 $\Omega$ Series Resistors in the Outputs

#### **General Description**

The ABT162244 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Individual 3-STATE control inputs can be shorted together for 8-bit or 16-bit operation.

The  $25\Omega$  series resistors in the outputs reduce ringing and eliminate the need for external resistors.

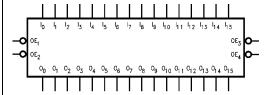
#### **Features**

- Separate control logic for each nibble
- 16-bit version of the ABT2244
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability

### **Ordering Code:**

Order Number	Package Number	Package Description
74ABT162244CSSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide [RAIL]
74ABT162244CSSX	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide [TAPE and REEL]
74ABT162244CMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [RAIL]
74ABT162244MTDX	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [TAPE and REEL]

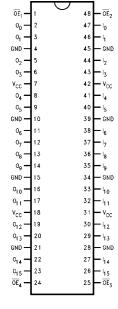
### **Logic Symbol**



### **Pin Descriptions**

Pin Names	Description
<del>OE</del> <sub>n</sub>	Output Enable Input (Active LOW)
I <sub>0</sub> –I <sub>15</sub>	Inputs
O <sub>0</sub> -O <sub>15</sub>	Outputs

## **Connection Diagram**



## **Truth Tables**

Inj	outs	Outputs
OE <sub>1</sub>	I <sub>0</sub> -I <sub>3</sub>	O <sub>0</sub> -O <sub>3</sub>
L	L	L
L	Н	Н
Н	X	Z

In	outs	Outputs
OE₃	I <sub>8</sub> -I <sub>11</sub>	O <sub>8</sub> -O <sub>11</sub>
L	L	L
L	Н	Н
Н	X	Z

In	puts	Outputs
OE <sub>2</sub>	I <sub>4</sub> –I <sub>7</sub>	O <sub>4</sub> -O <sub>7</sub>
L	L	L
L	Н	н
Н	X	Z

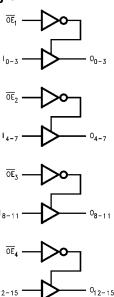
In	puts	Outputs
OE <sub>4</sub>	I <sub>12</sub> -I <sub>15</sub>	O <sub>12</sub> -O <sub>15</sub>
L	L	L
L	Н	Н
н	X	Z

- L
  H = HIGH Voltage Level
  L = LOW Voltage Level
  X = Immaterial
  Z = High Impedance

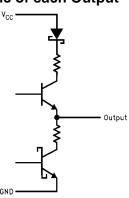
### **Functional Description**

The ABT162244 contains sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

## **Logic Diagram**



## **Schematic of each Output**



### **Absolute Maximum Ratings**(Note 1)

-65°C to +150°C Storage Temperature -55°C to +125°C Ambient Temperature under Bias

Junction Temperature under Bias -55°C to +150°C -0.5V to +7.0V

V<sub>CC</sub> Pin Potential to Ground Pin

Input Voltage (Note 2) -0.5V to +7.0VInput Current (Note 2) -30 mA to +5.0 mA

Voltage Applied to Any Output

in the Disabled or

Power-Off State -0.5V to 5.5Vin the HIGH State -0.5V to  $V_{CC}$ 

Current Applied to Output

in LOW State (Max) twice the rated  $I_{OL}$  (mA) DC Latchup Source Current -500 mA

Over Voltage Latchup (I/O) 10V

### **Recommended Operating Conditions**

-40°C to +85°C Free Air Ambient Temperature Supply Voltage +4.5V to +5.5V

Minimum Input Edge Rate ( $\Delta V/\Delta t$ )

50 mV/ns Data Input 20 mV/ns Enable Input

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation

under these conditions is not implied. Note 2: Either voltage limit or current limit is sufficient to protect inputs.

## **DC Electrical Characteristics**

Symbol	Paramet	er	Min	Тур	Max	Units	V <sub>CC</sub>	Conditions
V <sub>IH</sub>	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
V <sub>IL</sub>	Input LOW Voltage				0.8	V		Recognized LOW Signal
V <sub>CD</sub>	Input Clamp Diode Voltag	е			-1.2	V	Min	I <sub>IN</sub> = -18 mA
V <sub>OH</sub>	Output HIGH Voltage		2.5			V	Min	I <sub>OH</sub> = -3 mA
			2.0			V	Min	I <sub>OH</sub> = -32 mA
V <sub>OL</sub>	Output LOW Voltage				8.0	V	Min	I <sub>OL</sub> = 12 mA
I <sub>IH</sub>	Input HIGH Current				1	μА	Max	V <sub>IN</sub> = 2.7V (Note 3)
					1	μΛ	IVIAX	$V_{IN} = V_{CC}$
I <sub>BVI</sub>	Input HIGH Current Break	down Test			7	μА	Max	V <sub>IN</sub> = 7.0V
I <sub>IL</sub>	Input LOW Current				-1	μА	Max	V <sub>IN</sub> = 0.5V (Note 3)
					-1	μΑ	IVIAX	$V_{IN} = 0.0V$
V <sub>ID</sub>	Input Leakage Test		4.75			V	0.0	$I_{ID} = 1.9 \mu A$
								All Other Pins Grounded
I <sub>OZH</sub>	Output Leakage Current				10	μА	0 – 5.5V	$V_{OUT} = 2.7V; \overline{OE}_n = 2.0V$
I <sub>OZL</sub>	Output Leakage Current				-10	μА	0 – 5.5V	$V_{OUT} = 0.5V; \overline{OE}_n = 2.0V$
los	Output Short-Circuit Curre	ent	-100		-275	mA	Max	V <sub>OUT</sub> = 0.0V
I <sub>CEX</sub>	Output High Leakage Cur	rent			50	μА	Max	V <sub>OUT</sub> = V <sub>CC</sub>
I <sub>ZZ</sub>	Bus Drainage Test				100	μА	0.0	V <sub>OUT</sub> = 5.5V; All Others GND
I <sub>CCH</sub>	Power Supply Current				2.0	mA	Max	All Outputs HIGH
I <sub>CCL</sub>	Power Supply Current				60	mA	Max	All Outputs LOW
I <sub>CCZ</sub>	Power Supply Current				2.0	mA	Max	OE <sub>n</sub> = V <sub>CC</sub>
								All Others at V <sub>CC</sub> or GND
I <sub>CCT</sub>	Additional I <sub>CC</sub> /Input	Outputs Enabled			3.0	mA		V <sub>I</sub> = V <sub>CC</sub> - 2.1V
		Outputs 3-STATE			3.0	mA	Max	Enable Input V <sub>I</sub> = V <sub>CC</sub> - 2.1V
		Outputs 3-STATE			50	μΑ		Data Input V <sub>I</sub> = V <sub>CC</sub> - 2.1V
								All Others at V <sub>CC</sub> or GND
I <sub>CCD</sub>	Dynamic I <sub>CC</sub>	No Load				mA/	<b></b>	Outputs OPEN
	(Note 3)				0.1	MHz	Max	OE <sub>n</sub> = GND
								One Bit Toggling, 50% Duty Cycle

Note 3: Guaranteed, but not tested.

## **AC Electrical Characteristics**

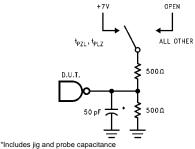
Symbol	Parameter		$T_A = +25^{\circ}C$ $V_{CC} = +5V$ $C_L = 50 \text{ pF}$		V <sub>CC</sub> = 4.	C to +85°C .5V–5.5V 50 pF	Units
		Min	Тур	Max	Min	Max	
t <sub>PLH</sub>	Propagation	1.0	2.4	3.9	1.0	3.9	ns
t <sub>PHL</sub>	Delay Data to Outputs	1.0	3.2	4.7	1.0	4.7	115
t <sub>PZH</sub>	Output	1.5	3.5	6.3	1.5	6.3	ns
$t_{PZL}$	Enable Time	1.5	4.2	6.9	1.5	6.9	115
t <sub>PHZ</sub>	Output	1.0	4.2	6.7	1.0	6.7	200
$t_{PLZ}$	Disable Time	1.0	3.8	6.7	1.0	6.7	ns

## Capacitance

Symbol	Parameter	Тур	Units	Conditions T <sub>A</sub> = 25°C
C <sub>IN</sub>	Input Capacitance	5.0	pF	V <sub>CC</sub> = 0.0V
C <sub>OUT</sub> (Note 4)	Output Capacitance	9.0	pF	V <sub>CC</sub> = 5.0V

 $\textbf{Note 4: } C_{OUT} \text{ is measured at frequency } f = 1 \text{ MHz per MIL-STD-883, Method 3012.}$ 

## **AC Loading**



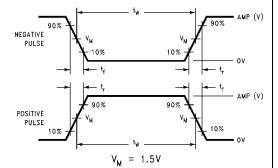


FIGURE 1. Standard AC Test Load

FIGURE 2. Input Pulse Requirements

3.0V 1 MHz 500 ns 2.5 ns 2.5 n	Amplitude	Rep. Rate	t <sub>W</sub>	t <sub>r</sub>	t <sub>f</sub>
****	3.0V	1 MHz	500 ns	2.5 ns	2.5 ns

FIGURE 3. Test Input Signal Requirements

#### **AC Waveforms**

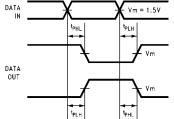


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

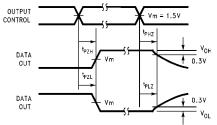


FIGURE 6. 3-STATE Output HIGH and LOW Enable and Disable Times

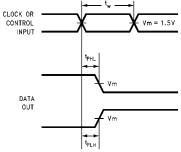


FIGURE 5. Propagation Delay, Pulse Width Waveforms

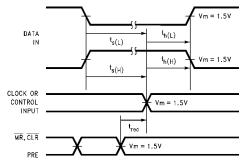
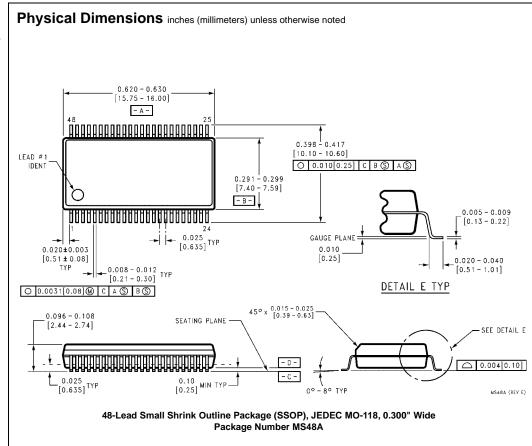
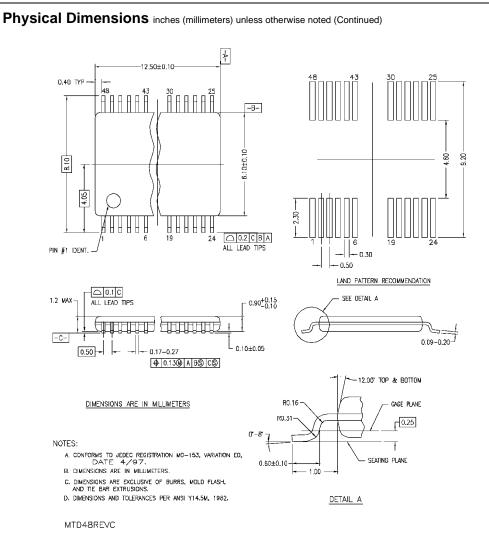


FIGURE 7. Setup Time, Hold Time and Recovery Time Waveforms





48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD48

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